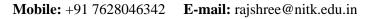
DR. RAJSHREE RAJKUMARI

Assistant Professor

Dept. of Electronics & Communication Engineering NITK Surathkal, Mangaluru, Karnataka 575025





Personal Profile

Date of Birth:	17-10-1990 (34 years)
Father's Name:	R.K. Budhi singh
Marital Status:	Married
Sex:	Female
Nationality:	Indian
Religion:	Meitei
Permanent Address:	Khurai Sajor Leikai ,Ukhrul Road, Imphal(E)
	Manipur- 795010, India

Education

	Name of course	Name of the Board/ University	Year of passing	Subjects studied
	(a)	(b)	(c)	(d)
10th Class	AISSE	CBSE	2005	English, Manipuri, Maths, Science, Social Science
10+2	AISSCE	CBSE	2007	English, Physics, Chemis try, Biology, Maths, Painting
Bachelor's degree	B.E	MANIPUR UNIVERSITY	2007-2011	Electronics & Communication Engineering
Master's degree	M.Tech	Assam Don Bosco University	2012-2014	Electronics & Communication Engineering
Ph. D.	Ph.D.	National Institute of Technology Nagaland	2016- 2021	Title: Studies on GLAD synthesized WO ₃ nanowires and silver nanoparticle decorated WO ₃ nanowires based photodetector and non-volatile memory

Area of Interest

Core Areas of Specialization	Current Research Interests	
Optoelectronics and Memory devices	Fabrication of nanostructures based photodetector, Solar cells and Non volatile Memory applications.	

Work Experience

- ➤ Served as Assistant Professor (Contract) in the Dept. of ECE, IIIT Manipur from 13th December, 2022 to 16th December, 2024
- ➤ Worked as Research Fellow from May 1, 2022 to November 30, 2022 in the Dept. of Materials Science and Engineering, Kyushu University, Japan-819 0395.
- > Served as Teaching Assistant from September 2016 to November 2020 in the Department of Electronics & Communication Engineering, National Institute of Technology Nagaland, Dimapur-797103, Nagaland.

Technical Skills

- ➤ Operation of Electron Beam Evaporator, Ball Milling and sputtering.
- ➤ Oblique angle deposition and glancing angle deposition techniques for nanowires, thin film and nanoparticle fabrication.
- ➤ Fabrication of ultraviolet Schottky diode (nanowires as well as thin film devices) as well as non volatile memory device.
- > Silicon paste preparation for solar cells
- > I-V and C-V measurement of the devices.
- > XRD, FTIR, Absorption measurement.
- ➤ Operation of Quartz Tube Furnace and Hot Press

Publications

- 1. Rajkumari, R., Alam, M. W., Souayeh, B., & Singh, N. K. (2024). Improvement of capacitive and resistive memory in WO_3 thin film with annealing. Journal of Materials Science, 59(8), 3270-3283.
- 2. Rajkumari, R., Sadaf, S., Alam, M. W., & Singh, N. K. (2024). Self-Powered Photodetector with High Sensitivity Based on a CeO₂/TiO₂ Thin Film. ACS Applied Electronic Materials, 6(5), 3532-3538.
- 3. Lynrah, S. A., Chinnamuthu, P., Rajkumari, R., Lim, Y. Y., Walling, L., & Vigneash, L. (2024). Surface functionalization of MnO_2 NW embellished with metal nanoparticles for self-cleaning applications. Applied Nanoscience, 14(3), 519-529.
- 4. Rajkumari, R. Ngangbam C, and Singh, N.K., High Detectivity Photodetector Based on WO₃ Nanowires by the Surface Plasmonic Effect of Ag Nanoparticles, IEEE Electron Device Letters, Vol. 43, No. 3, pp. 470., January, 2022.
- 5. C. Ngangbam, Rajkumari, R. L. Thoibileima, M. W. Alam and Singh, N.K., "High Responsivity of GLAD Synthesized Isotype WO₃/In₂O₃ Nanocluster," in IEEE Photonics Technology Letters, Vol. 33, No. 17, pp. 943-946., September, 2021.
- 6. N.M. Devi, S.A. Lynrah, Rajkumari, R. and Singh, N.K., Effect of Ag decoration on the Photodetection of Catalyst-Free Synthesized Vertically Oriented SiOx NW arrays, Sensors and Actuators A: Physical, Vol. 327, pp. 112744., August, 2021.
- 7. Rajkumari, R., Ngangbam, C. and Singh, N.K., Presence of capacitive memory in GLAD-synthesized WO₃ nanowire, Journal of Materials Science: Materials in Electronics, Vol. 32, No. 3, pp.3191-3200., January, 2021.
- 8. Rajkumari, R. and Singh, N.K., Ag Nanoparticle-Decorated WO₃ Nanowires for Nonvolatile Memory, ACS Applied Nano Materials, Vol. 3, No. 12, pp. 12087-12094, December, 2020.
- 9. S. Meitei, Rajkumari, R. and Singh, N.K., Post deposition annealing effect on the electrical properties of β -Ga₂O₃ Nanowire, Journal of Materials Science: Materials in Electronics, Vol. 31, No. 22, pp. 20378-20386, September, 2020.
- 10. Rajkumari, R. and Singh, N.K., Effect of Annealing on Morphology and Photoluminescence of WO₃ Nanowires Deposited by Glancing Angle Deposition Techniques, Journal of Nanoscience and Nanotechnology, Vol. 20, No. 5, pp. 3274-3282., May, 2020.
- 11. Rajkumari, R. and Singh, N.K., Effect of annealing on the structural and electrical properties of GLAD synthesized vertical aligned WO₃ nanowire, IEEE Transactions on Nanotechnology, Vol. 18, pp. 676-683, July, 2019.

12. Rajkumari, R. and Singh, N.K., Influence of annealing on the optoelectronic properties of the GLAD synthesized SiOx–ZnO heterostructure nanoclusters, Applied Physics A, Vol. 124, No. 3, pp.1-8., February, 2018.

Book Chapter

1. Singh, N. K., & Rajkumari, R. (2019). Effect of annealing on metal-oxide nanocluster. In Concepts of Semiconductor Photocatalysis. IntechOpen.

CONFERENCE:

- 1. R. Rajkumari, and N.K. Singh, "Electron Beam Evaporated WO3 Thin Film as UV-A Photodetector" International Conference on Nano Technology for better living (ICNBL-2021)" held from 7th to 11th September 2021 at National Institute of Technology, Srinagar, India (Best oral presentation awarded).
- 2. Lusato Mashaka Majula, Matsuo Seiya, R. Rajkumari, Yoshimine Kato, "Fabrication of pn-junction by doping into a nano-crystalline Si paste made from poly-Si raw material" 33rd International Photovoltaic Science and Engineering Conference (PVSEC-33) from 3 to 17 November 2022, Nagoya Japan.

Award and Honors

- Recipient of MHRD Scholarship (Ph.D.)
- Best Oral Presentation at the International Conference on "Nanotechnology for Better Living" (NBL-2021) for the paper titled "Electron Beam Evaporated WO₃ Thin Film as UV-A Photodetector," organized by the National Institute of Technology Srinagar, from 7-11 September, 2021.

I hereby declare that all particulars stated above are true to the best of my knowledge and belief.

Thanking you

Date: 26/12/2024

Place: Mangalore

Rajshree Rajkumari

Signature